

NEC's GENERAL PURPOSE 5 V AGC AMPLIFIER

UPC3221GV

FEATURES

- ON-CHIP LOW DISTORTION AMPLIFIER: IIP3 = +2.5 dBm at minimum gain
- WIDE AGC DYNAMIC RANGE: GCR = 50 dB TYP
- ON-CHIP VIDEO AMPLIFIER:
 VOUT = 1.0 VP-P at single-ended output
- SUPPLY VOLTAGE: Vcc = 5 V
- PACKAGED IN 8 PIN SSOP SUITABLE FOR SURFACE MOUNTING
- LOW NOISE FIGURE: 4.2 dB TYP

DESCRIPTION

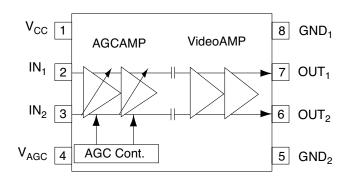
NEC's UPC3221GV is a Silicon Monolithic IC designed for use as an AGC Amplifier for digital CATV, cable modem and IP telephony systems. This IC consists of a two stage gain control amplifier and a fixed gain video amplifier. The device provides a differential input and differential output for noise performance, which eliminates shielding requirements.

The package is 8-pin SSOP (Shrink Small Outline Package) suitable for surface mount.

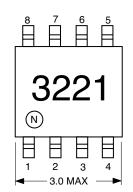
This IC is manufactured using NEC's 10 GHz ft NESAT $^{\text{TM}}$ II AL silicon bipolar process. This process uses silicon nitride passivation film. This material can protect chip surface from external pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.

INTERNAL BLOCK DIAGRAM AND PIN CONFIGURATION



PACKAGE OUTLINE S08



All dimensions are typical unless specified otherwise.

APPLICATIONS

- Digital CATV
- · Cable modem receivers
- · IP Telephony receivers

ELECTRICAL CHARACTERISTICS

(TA = 25°C, Vcc = 5 V, Zs = 1K Ω , ZL = 1K Ω , fin = 45 MHz, single-ended output), unless otherwise noted

PART NUMBER PACKAGE OUTLINE				UPC3221GV S08		
DC Characte	ristics					
I _{CC}	Circuit Current ¹ (no input signal)	mA	26	33	41	
I _{AGC} (H)	AGC Pin Current ¹ , No input Signal, V _{AGC} = 3.5 V	V	_	16	50	
V _{AGC} (H)	AGC Voltage High Level ¹ , at Maximum gain	V	3.0	_	3.5	
V _{AGC} (L)	AGC Voltage Low Level ¹ , at Minimum gain	V	0	_	0.5	
RF Characte	ristics					
G _{MAX}	Maximum Gain ¹ , VAGC = 3.0 V, P _{in} = -60 dBm	dB	57	60	63	
G _{MID} 1	Middle Gain 1 ¹ , VAGC = 2.2 V, P _{in} = -60 dBm	dB	47.5	50.5	53.5	

ELECTRICAL CHARACTERISTICS, cont.

(TA = 25°C, Vcc = 5 V, fin = 45 MHz, Zs = 50Ω , ZL = 250Ω , single-ended output), unless otherwise noted

PART NUMBER PACKAGE OUTLINE					UPC3221GV S08		
RF Characte	ristics						
G _{MID} 2	Middle Gain 2 ¹ , VAGC = 1.2 V, PIN = -30 dBm	dB	18	21	24		
G _{MIN}	Minimum Gain ¹ , VAGC = 0.5 V, PIN = -30 dBm	dB	6	10	14		
G _{CRin}	Gain Control Range Input ¹ , V _{AGC} = 0.5 to 3.0 V	dB	43	50	_		
G _{CRout}	Gain Control Range Output ¹ , V _{out} = 1.0 V _{p-p}	dB	36	40	_		
G _{slope}	Gain Control Slope ¹ , Gain (at V _{AGC} = 2.2 V) - Gain (at V _{AGC} = 1.2 V)	dB	26.5	29.5	32.5		
V _{oclip}	Maximum Output Voltage ¹ , V _{AGC} = 3.0 V at maximum gain	V _{P-P}	2.0	2.8	_		
NF	Noise Figure ³ , V _{AGC} = 3.0 V at maximum gain	dB	-	4.2	5.7		
IM ₃ 1	Third Order Intermodulation Distortion ¹ , f_{IN1} = 44 MHz, f_{IN2} = 45 MHz, PIN = -30 dBm/tone, Vout = 0.7 V _{p-p} /tone at single ended output, Z _L = 250 Ω	dBc	43	47	_		
IM ₃ 2	Third Order Intermodulation Distortion 2, $fl_{N1}=44$ MHz, $f_{IN2}=45$ MHz, $V_{AGC}=3.0$ V at maximum gain, Vout = 0.7 V_{p-p} /tone at single ended output, $Z_L=250$ Ω	dBc	50	56	_		
ΔG	Gain ^{1,2} , V_{AGC} = 3.0 V, P_{in} = -60 dBm, Z_L = 250 Ω , ΔG = G at P_{out} 1- G at P_{out} 2	dB	-0.5	0	+0.5		

STANDARD CHARACTERISTICS (TA = 25°C, Vcc = 5 V, Zs = 50Ω), unless otherwise noted

	PART NUMBER	UPC3221GV		
	PACKAGE OUTLINE	S08		
SYMBOLS	PARAMETERS	UNITS	REFERENCE VALUE	
NF2	GAIN Recuction ³ = -10 dB	dB	6.0	
NF3	GAIN Recuction ³ = -20 dB	dB	9.5	
V_{out}	$P_{in}^{1} = -56 \text{ to } -16 \text{ dBm}$	V _{p-p}	1.0	
Z _{in}	Input Impedance ⁴ = 0.5 V, f = 45 MHz	Ω	0.9k - j1.4k	
Z_{out}	Output Impedance ⁴ = 0.5 V, f = 45 MHz	Ω	9.0+j1.9	
IIP ₃	3rd Order Input Intercept Point ¹ = V_{AGC} = 0.5 V at minmum gain, f ₁ = 44 MHz, f ₂ = 45 MHz, Z _L = 250 Ω at single ended output	dBm	+2.5	

Note

- 1. By measurement Circuit 1
- 2. By measurement Circuit 2
- 3. By measurement Circuit 3
- 4. By measurement Circuit 4

ABSOLUTE MAXIMUM RATINGS1,2

(Ta = 25°C, V_{CC} = 5 V, Z_{S} = 50 Ω , unless otherwise specified)

SYMBOLS PARAMETERS		UNITS	RATINGS
Vcc	Voltage Current	V	6.0
V _{AGC} (H)	AGC Voltage	V	0 to V _{CC}
P_{D}	Power Dissipation ²	mW	250
Та	Operating Ambient Temp.1	°C	-40 to +85
Тѕтс	Operating Ambient Temp.1	°C	-55 to +150

Notes:

- 1. Operation in excess of $\,$ any one of these parameters may result in permanent damage.
- 2. Mounted on a 50 x 50 x 1.6 mm epoxy glass PWB, with copper patterning on both sides, $T_A = 85^{\circ}C$

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	UNITS	MIN	TYP	MAX
Vcc	Supply Voltage	V	4.5	5.0	5.5
Та	Operating Ambient Temp. ¹	°C	-40	+25	+85
VAGC	Gain Control Voltage Range	V	0	_	3.5
fвw	Video Input Signal Range	dBmV	10	45	100

Note:

1. Vcc = 4.5 to 5.5 V

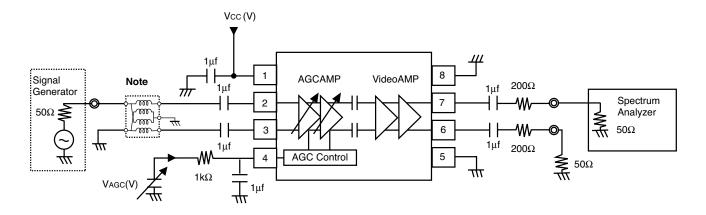
PIN EXPLANATIONS

Pin No.	Name	Applied Voltage (v)	Pin Voltage (v) ¹	Description	Internal Equivalent Circuit
1	Vcc	4.5 to 5.5		Power supply pin. This pin should be externally equipped with bypass capacitor to minimize ground impedance.	
2	INPUT1		1.29	Signal input pins of AGC amplifier.	0 ***
3	INPUT2		1.29		AGC Control
4	Vagc	0 to Vcc		Gain control pin. This pin's bias govern the AGC output level. Minimuim Gain at VAGC = 0.5 V Maximum Gain at VAGC = $3 \text{ to } 3.5 \text{ V}$ Recommended to use by dividing AGC voltage with external resistor (ex. $1\text{k}\Omega$)	AGC Amp
5	GND 2	0		Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible.	
6	OUTPUT2		2.28	Signal output pins of video amplifier	1
7	OUTPUT1		2.28		(a) (b) (c) (c) (c) (c) (c) (c) (c) (c) (c) (c
8	GND 1	0		Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All ground pins must be connected together with wide ground pattern to decrease impedance difference.	

Note:

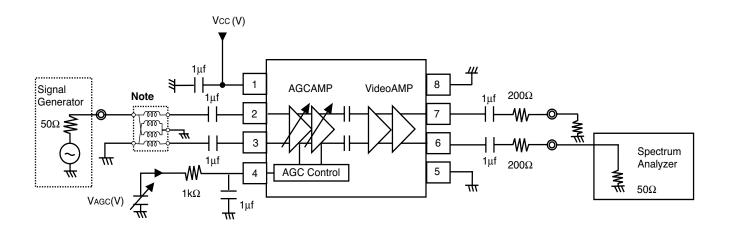
1. Pin is measured at Vcc = 5 V

MEASUREMENT CIRCUIT 1



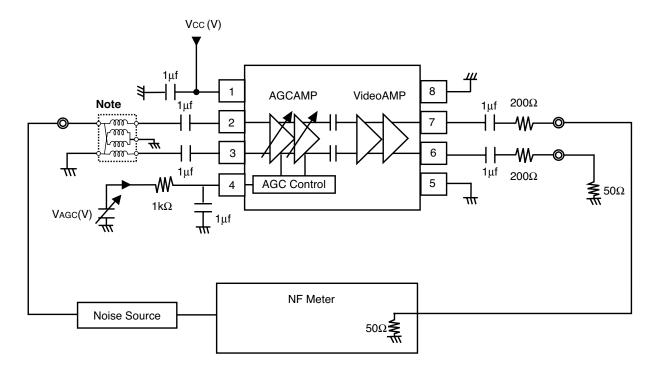
Note: Balun Transformer: TOKO 617DB-1010 B4F (Double balanced type)

MEASUREMENT CIRCUIT 2



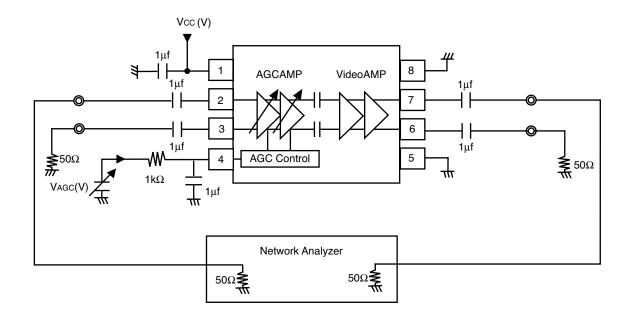
Note: Balun Transformer : TOKO 617DB-1010 B4F (Double balanced type)

MEASUREMENT CIRCUIT 3



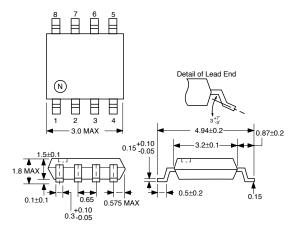
Note: Balun Transformer: TOKO 617DB-1010 B4F (Double balanced type)

MEASUREMENT CIRCUIT 4



OUTLINE DIMENSIONS (Units in mm)

PACKAGE OUTLINE S08



All dimensions are typical unless specified otherwise.

ORDERING INFORMATION

PART NUMBER	QUANTITY	
UPC3221GV-E1-A	1 kp/reel	

Note:

Embossed tape 8 mm wide. Pin 1 indicates pull-out direction of tape.

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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DATA SUBJECT TO CHANGE WITHOUT NOTICE

07/28/2003



Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration in CEL		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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